

Positive Fixed 8V Voltage Regulator in bare die form

Rev 1.0 3/06/25

Description

The 7808 8V fixed 3-terminal positive voltage regulator delivers up to 1.5A of output current with adequate heat-sinking. The device is equipped with internal limiting, safe-area compensation + thermal shutdown features for overload immunity. The 7808 can be used with external components to obtain adjustable voltages or currents & can also be used as the power-pass element in precision high-current voltage regulators. No external components are needed other than to enhance performance or increase design flexibility.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection+ MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

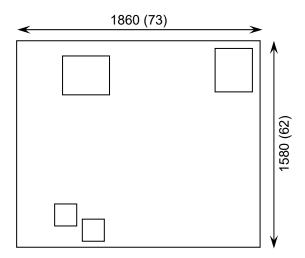
Supply Formats:

- Default Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Features:

- ±5% V_{OUT} tolerance over entire temperature range
- Greater than 1A output current capability
- Internal thermal overload protection
- Internal short-circuit current limit
- Output capacitor not essential for stability
- Full Military temperature range
- Negative voltage complement is 7908

Die Dimensions in µm (mils)



Mechanical Specification

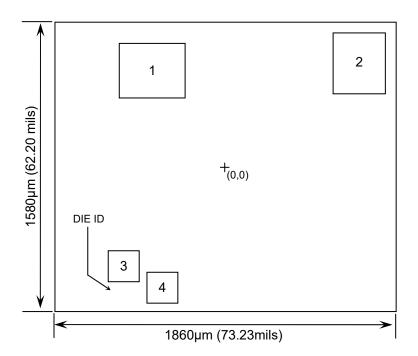
Die Size (Unsawn)	1860 x 1580 73 x 62	µm mils	
Minimum Bond Pad Size	165 x 165 6.49 x 6.49	μm mils	
Die Thickness	280 (±20) 11.02 (±0.79)	μm mils	
Top Metal Composition	Al-Si-Cu		
Back Metal Composition	Ti/Ni/Ag		





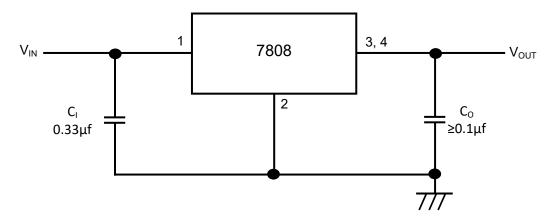
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Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)			
PAU	FUNCTION	X	Y		
1	V _{IN}	-400.5	526.5		
2	GND	730.5	567		
3	V _{OUT}	-345.5	-657.5		
4	V _{OUT}	-554.5	-541.5		
CONNECT CHIP BACK TO GND					

Typical Application



 $C_{\rm l}$ is required if the regulator is located an appreciable distance from power supply filter. $C_{\rm O}$ is not required for stability; however it does improve transient response. For optimum stability and transient response locate $C_{\rm l}$ $C_{\rm O}$ as close as possible to the regulator. A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.





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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	SYMBOL VALUE	
Input Voltage	V _{IN}	35	V
Power Dissipation ²	P _D	Internally Limited	W
Operating Temperature Range	-	-55 to 125	°C
Maximum Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-65 to 150	°C

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V _{IN}	7	25	V
Output Current	I _{out}	-	1.5	A
Operating Temperature Range	T _J	-55	125	°C

DC Electrical Characteristics, V_i =14V, I_{OUT} =500mA, C_i =0.33 μ F, C_o =0.1 μ f, T_{MIN} \leq T $_J$ \leq T $_{MAX}$ (unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Output Voltage	V _{OUT}	T _J = 25°C	7.7	8.0	8.3		
		$5\text{mA} \le I_{\text{OUT}} \le 1\text{A},$ $10.5\text{V} \le V_{\text{IN}} \le 23\text{V}, P_{\text{D}} \le 15 \text{ Watts}$	7.6	8.0	8.4	V	
Line Regulation	A)/	$10.5V \le V_{IN} \le 25V, T_{J} = 25^{\circ}C$	-	-	160		
Line Regulation	ΔV _{OUT}	11V ≤ V _{IN} ≤ 17V, T _J = 25°C	-	-	80	mV	
Load Regulation	ΔV_{OUT}	$5\text{mA} \le I_{\text{OUT}} \le 1.5\text{A}, T_{\text{J}} = 25^{\circ}\text{C}$	-	-	160		
Input Bias Current	I _B		-	-	8	mA	
Input Bias Current	Δl _B	10.5V ≤ V _{IN} ≤ 25V	-	-	1	mΛ	
Change		5mA ≤ I _{OUT} ≤ 1A, T _J = 25°C	-	-	0.5	mA	
Output Noise Voltage	V _n	10Hz ≤ f ≤ 100KHz, T _J = 25°C	-	10	-	μV/V _{OUT}	
Ripple Rejection	RR	$11.5V \le V_{IN} \le 18V$, f = 120Hz,	-	73	-	dB	
Dropout Voltage	V _{IN} – V _{OUT}	I _{OUT} = 1A, T _J = 25°C	-	2	-	V	
Output Resistance	r _{OUT}	f = 1 kHz	-	0.9	-	mΩ	
Short-Circuit Current Limit	I _{SC}	V _{IN} = 35V, T _A = 25°C	-	0.2	-	Α	
Peak Output Current	I _{MAX}	T _J = 25°C	-	1.8	-	Α	
Avg. Output Voltage Temp. Coefficient	TCV _{OUT}		-	-0.4	-	mV/°C	

^{1.} Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Results in die form are dependent on die attach and assembly method. Max power dissipation is internally limited by the die.





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Typical Characteristics

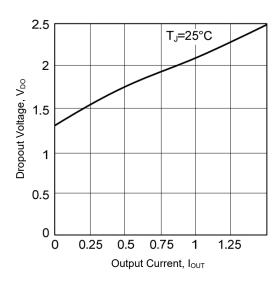
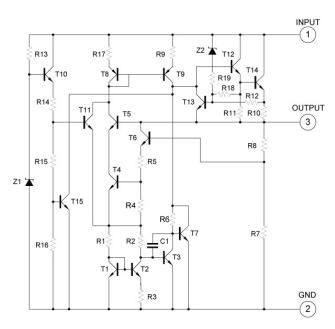


Figure 1 - Dropout Voltage Versus Output Current

Internal Schematic



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